

20A Avg.

30 Volts

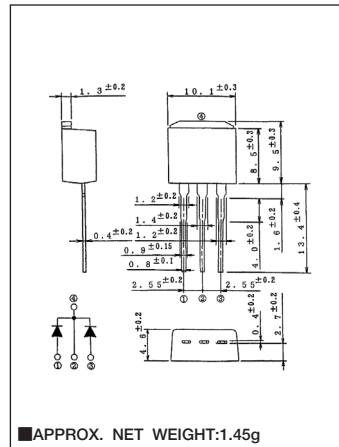
SBD

C20T03QL-11A

■最大定格 Maximum Ratings

| Item | Symbol | Conditions | Unit |
|--|------------|--|----------------------|
| くり返しピーク逆電圧 Repetitive Peak Reverse Voltage | V_{RRM} | 30 | V |
| くり返しピークサージ逆電圧 Repetitive Peak Surge Reverse Voltage | V_{RRSM} | 35 pulse width $\leq 1 \mu s$ duty $\leq 1/50$ | V |
| 平均整流電流 Average Rectified Forward Current | I_O | 50Hz、正弦全波通電抵抗負荷 50Hz Full Sine Wave Resistive Load | $T_c=119^\circ C$ 20 |
| 実効順電流 R.M.S. Forward Current | $I_F(RMS)$ | 22.2 | A |
| サージ順電流 Surge Forward Current | I_{FSM} | 180 50Hz正弦全波、1サイクル、非くり返し 50Hz Full Sine Wave, 1 cycle, Non-repetitive | A |
| 動作接合温度範囲 Operating Junction Temperature Range | T_{jw} | -40 ~ +150 | $^\circ C$ |
| 保存温度範囲 Storage Temperature Range | T_{stg} | -40 ~ +150 | $^\circ C$ |

■OUTLINE DRAWING(mm)



■電氣的・熱的特性 Electrical/Thermal Characteristics

| Item | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|--------------------------------|---------------|--|------|------|------|--------------|
| ピーク逆電流 Peak Reverse Current | I_{RM} | $T_j=25^\circ C, V_{RM}=V_{RRM}$, 一素子あたり Per Diode | — | — | 10 | mA |
| ピーク順電圧 Peak Forward Voltage | V_{FM} | $T_j=25^\circ C, I_{FM}=10A$, 一素子あたり Per Diode | — | — | 0.49 | V |
| 熱抵抗 Thermal Resistance | $R_{th(j-c)}$ | 接合部・ケース間 Junction to Case | — | — | 1.5 | $^\circ C/W$ |

■定格・特性曲線

